PROBLEM REPORT PR-1036 SEP LVPS 2005-02-27

Assembly : SEP	LVPS	PS SubAssembly : Top and Middle Boar	
Component/Part Number:		Serial Number: FM2 and FM1	
SEP TOP F001	and SEP Middle F001		
Originator: Selda Heavner		Organization: U.C. Berkeley	
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Environment wh	en failure occurred:		
$\sqrt{\text{Ambient}}$	\Box Vibration	□ Shock	□ Acoustic
		□ Thermal-Vacuum	□ EMI/EMC
Thermal			

SEP LVPS FM2 was intermittently consuming high current at turn-on. The high-current at turn-on did not reach 0.90A which is the recommended current limit for the bench supply. It typically remained at 580-600mA range. The 28V line did not change when the Supply was consuming 580mA and remained at 28.0V. The supply was not left in the high current state for longer than 30 seconds.

Analyses Performed to Determine Cause

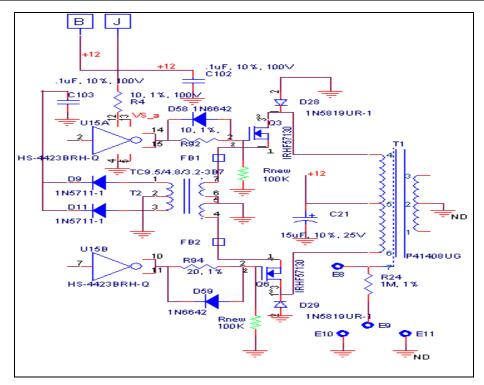
SEP ETU Unit was tested using the bench supply from Caltech KIKUSUI PMC35-1A. SEP ETU was turned on and off until the problem was reproduced. When the high-current occurred the switching FETS became extremely hot. The FETs were still functional after leaving the high-current on a long time. Therefore, the problem is with the FET drivers (for the switching FETs that drive the transformers). When the drivers first come on they set their output to high impedance until their supply voltage exceeds some threshold. So the FET gate floats, and depending on leakage currents the FET can turn on providing a low impedance short (through the transformer windings) on the primary regulator. This in turn causes the voltage regulator to go into current limit so the voltage never gets over the turn-on threshold for the FET driver. So the difference between supplies (and between bench supplies that come up slower or faster) is if the leakage current is large enough to charge up the gate before the primary regulator voltage gets high enough to turn on the driver.

The circuit was analyzed to determine if any parts were stressed by this condition. The FETs were the only candidates, and while the duration was probably too short to damage the FETs, they were replaced anyway (Q3, Q6, Q11, Q14, Q22, Q15, Q18, Q20 on the middle board, and Q10, Q12, Q19, and Q21 on the top board).

Corrective Action/ Resolution					
√ Rework	□ Repair	\Box Use As Is	□ Scrap		

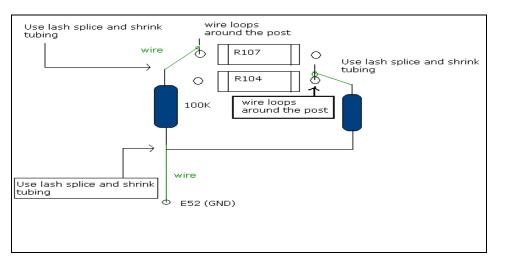
100K Ω resistor from the FET gate to ground can hold the FETs off when the driver is in high impedance mode. This solution was incorporated on ETU and the problem could not be reproduced. Figure 1 indicates where the new resistors (Rnew) will be connected for the Top and Middle Board.

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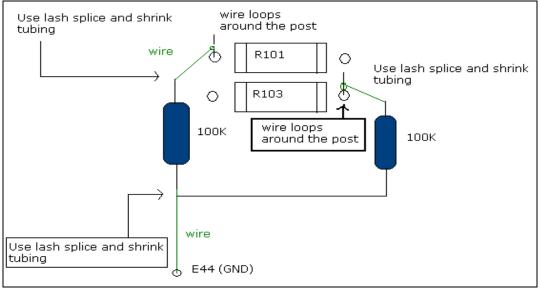


For the Middle Board

- 1- Connect a small post on R107 (D68 anode side).
- 2- Connect #24AWG wire on the small post installed.
- 3- Connect a $100K\Omega$ (RNC50H1003FR) to the wire using lash splice. The wire must be as short as possible. The additional resistors must be close to the corresponding gate drive.
- 4- Put shrink tubing over where wire and the resistor are soldered.
- 5- Install a small post on R104 (D66 anode side)
- 6- Connect #24AWG wire on the small post installed.
- 7- Connect a $100K\Omega$ (RNC50H1003FR) to the wire using lash splice. The wire must be as short as possible. The additional resistors must be close to the corresponding gate drive
- 8- Connect the other side of the resistors and #24AWG together using lash splice.
- 9- Cover the connection with shrink tubing.

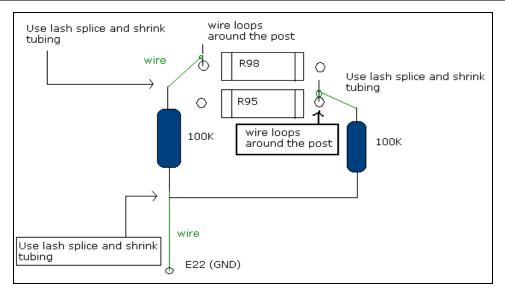


- 10- Connect the wire to E52.
- 11- Stake the wires and additional resistors.
- 12- Connect a small post on R101 (D65 anode side).
- 13- Connect #24AWG wire on the small post installed.
- 14- Connect a $100K\Omega$ (RNC50H1003FR) to the wire using lash splice. The wire must be as short as possible. The additional resistors must be close to the corresponding gate drive.
- 15- Put shrink tubing over where wire and the resistor are soldered.
- 16- Install a small post on R103 (D64 anode side)
- 17- Connect #24AWG wire on the small post installed.
- 18- Connect a 100K Ω (RNC50H1003FR) to the wire using lash splice. The wire must be as short as possible. The additional resistors must be close to the corresponding gate drive
- 19- Connect the other side of the resistors and #24AWG together using lash splice.
- 20- Cover the connection with shrink tubing.
- 21- Connect the wire to E44.
- 22- Stake the wires and additional resistors.

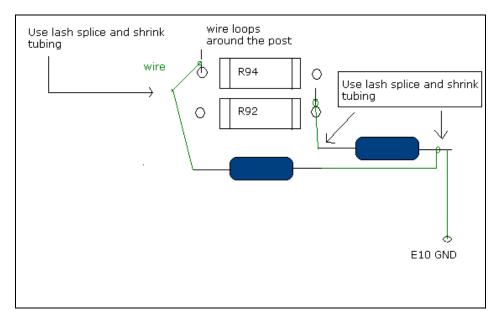


- 23- Connect a small post on R98 (D62 anode side).
- 24- Connect #24AWG wire on the small post installed.
- 25- Connect a $100K\Omega$ (RNC50H1003FR) to the wire using lash splice. The wire must be as short as possible. The additional resistors must be close to the corresponding gate drive.
- 26- Put shrink tubing over where wire and the resistor are soldered.
- 27- Install a small post on R95 (D60 anode side)
- 28- Connect #24AWG wire on the small post installed.
- 29- Connect a 100K Ω (RNC50H1003FR) to the wire using lash splice. The wire must be as short as possible. The additional resistors must be close to the corresponding gate drive
- 30- Connect the other side of the resistors and #24AWG together using lash splice.
- 31- Cover the connection with shrink tubing.
- 32- Connect the wire to E22.
- 33- Stake the wires and additional resistors.

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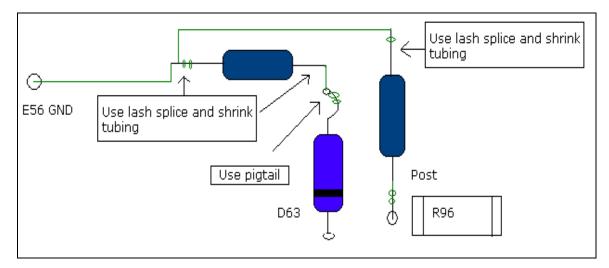
- 34- Connect a small post on R94 (D59 anode side).
- 35- Connect #24AWG wire on the small post installed.
- 36- Connect a $100K\Omega$ (RNC50H1003FR) to the wire using lash splice. The wire must be as short as possible. The additional resistors must be close to the corresponding gate drive.
- 37- Put shrink tubing over where wire and the resistor are soldered.
- 38- Install a small post on R92 (D58 anode side)
- 39- Connect #24AWG wire on the small post installed.
- 40- Connect a $100K\Omega$ (RNC50H1003FR) to the wire using lash splice. The wire must be as short as possible. The additional resistors must be close to the corresponding gate drive
- 41- Connect the other side of the resistors and #24AWG together using lash splice.
- 42- Cover the connection with shrink tubing.
- 43- Connect the wire to E10
- 44- Stake the wires and added resistors.



- 45- Replace Q3, Q6, Q14, Q11, Q22, Q15, Q18 and Q20. (IRHF57130SCS)
- 46- Coat transistors that were replaced using Uralane 5750.

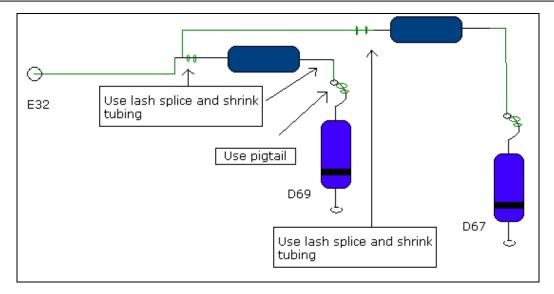
For the TOP Board

- 47- Connect a small post on R96 (D61 anode side).
- 48- Connect #24AWG wire on the small post installed.
- 49- Connect a 100K Ω (RNC50H1003FR) to the wire using lash splice. The wire must be as short as possible. The additional resistors must be close to the corresponding gate drive.
- 50- Put shrink tubing over where wire and the resistor are soldered.
- 51- Remove D63
- 52- Install new D63 (JANTXV1N6642) with pigtail on its anode side.
- 53- Connect a wire on the pigtail.
- 54- Connect a 100K Ω (RNC50H1003FR) to the wire using lash splice
- 55- Connect the other side of the resistors and #24AWG together using lash splice.
- 56- Cover the connection with shrink tubing.
- 57- Connect the wire to E56
- 58- Stake the wires and added resistors.



- 59- Remove D67
- 60- Remove D69
- 61- Install new D67 (JANTXV1N6642) with pigtail on its anode side
- 62- Install new D69 (JANTXV1N6642) with pigtail on its anode side
- 63- Connect a 100KΩ (RNC50H1003FR) to anode of D67 using lash splice.
- 64- Connect a 100KΩ (RNC50H1003FR) to anode of D69 using lash splice.
- 65- Connect the other side of the resistors and #24AWG together using lash splice.
- 66- Cover the connection with shrink tubing.
- 67- Connect the wire to E32
- 68- Stake the wires and added resistors using Uralane 5753.
- 69- Replace Q10, Q12, Q19 and Q21 (IRHF57130SCS)
- 70- Coat the new transistors with Uralane 5750.

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 Date Action Taken:
 Retest Results:

 Corrective Action Required/Performed on other Units :
 Serial Number(s):SEP LVPS ETU

Closure Approvals

 Date: Date Date:
 Date: